



CT1110-W, CT1111-W, CT1112-W, CT1113-W, CT1114-W
CT1115-W, CT1116-W, CT1117-W, CT1118-W, CT1119-W
CT1110L-W, CT1111L-W, CT1112L-W, CT1113L-W, CT1114L-W
CT1115L-W, CT1116L-W, CT1117L-W, CT1118L-W, CT1119L-W
DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- Extra low coupling capacitance
- DC input with transistor output
- Operating Temperature range - 55 °C to 125 °C
- Green Package

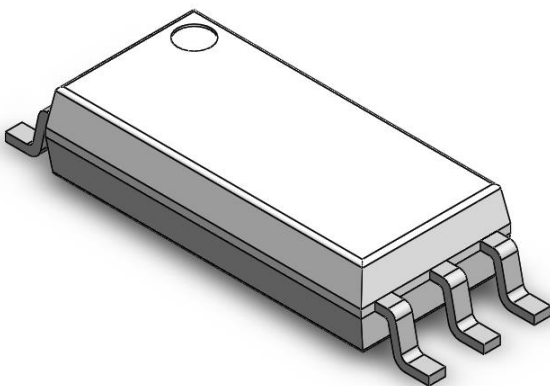
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

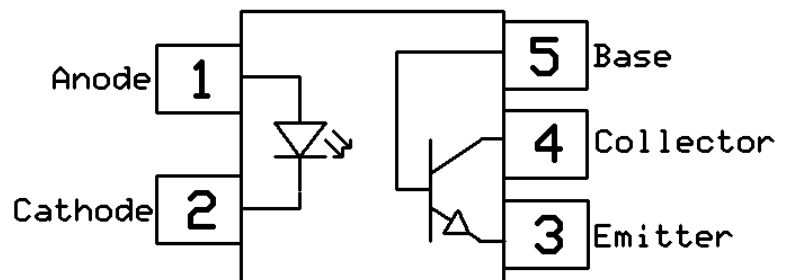
Description

The CT11XX-W, CT11XXL-W series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 5-lead SOP Package.

Package Outline



Schematic





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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Absolute Maximum Rating at 25°C

<i>Symbol</i>	<i>Parameters</i>	<i>Ratings</i>	<i>Units</i>	<i>Notes</i>
V _{ISO}	Isolation voltage *1	5000	V _{RMS}	
T _{OPR}	Operating temperature	-55 ~ +125	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature *2	260	°C	
Emitter				
I _F	Forward current	50	mA	
I _{F(TRANS)}	Peak transient current (≤1μs P.W,300pps)	1	A	
V _R	Reverse voltage	6	V	
P _D	Power dissipation	85	mW	
Detector				
P _D	Power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	7	V	
B _{VCBO}	Collector-Base Breakdown Voltage	80	V	
B _{VEBO}	Emitter-Base Breakdown Voltage	7	V	
I _C	Collector Current	50	mA	

Thermal Characteristics

<i>Symbol</i>	<i>Parameters</i>	<i>Ratings</i>	<i>Units</i>	<i>Notes</i>
R _{θJA}	Thermal Resistance Junction-Ambient	445	°C/W	
T _J	Junction temperature	125	°C	

Note:

1. Soldering Time: 10 seconds (max)



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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Electrical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward voltage	$I_F = 10\text{mA}$		1.24	1.4	V	
		$I_F = 50\text{mA}$	-	1.45	1.5	V	
I_R	Reverse Current	$V_R = 6\text{V}$	-	-	5	μA	
C_{IN}	Input Capacitance	$f = 1\text{kHz}$	-	45	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$B_{V_{CEO}}$	Collector-Emitter Breakdown	$I_C = 100\mu\text{A}$	80	-	-	V	
$B_{V_{ECO}}$	Emitter-Collector Breakdown	$I_E = 100\mu\text{A}$	7	-	-	V	
$B_{V_{CBO}}$	Collector-Base Breakdown	$I_C = 100\mu\text{A}$	80	-	-	V	
$B_{V_{EBO}}$	Emitter-Base Breakdown	$I_E = 100\mu\text{A}$	7	-	-	V	
I_{CEO}	Collector-Emitter Dark Current	$V_{CE} = 20\text{V}$	-	-	100	nA	
I_{CBO}	Collector-Base Dark Current	$V_{CB} = 20\text{V}$			20	nA	



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Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes	
CTR	Current Transfer Ratio	CT1110-W	I _F = 5mA, V _{CE} = 5V	50	-	600	%	
		CT1115-W		50	-	150		
		CT1116-W		100	-	300		
		CT1117-W		80	-	160		
		CT1118-W		130	-	260		
		CT1119-W		200	-	400		
		CT1111-W	I _F = 10mA, V _{CE} = 5V	60	-	300		
		CT1112-W		63	-	125		
		CT1113-W		100	-	200		
		CT1114-W		160	-	320		
		CT1100L-W	I _F = 1mA, V _{CE} = 5V	22	-	600		
		CT1101L-W		100	-	200		
		CT1102L-W		60	-	300		
		CT1103L-W		80	-	200		
		CT1104L-W		400	-	650		
		CT1105L-W		110	-	160		
		CT1106L-W		120	-	470		
		CT1107L-W		150	-	300		
		CT1108L-W		180	-	350		
CT1109L-W	300	-	400					
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	I _F = 10mA, I _C = 1mA	-	-	0.4	V		
R _{IO}	Isolation Resistance	V _{IO} = 500V _{DC}	5x10 ¹⁰			Ω		
C _{IO}	Isolation Capacitance	f= 1MHz			1	pF		

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
T _{ON}	Turn On Time	I _C = 5mA, V _{CE} = 5V, R _L = 100Ω	-	5	-	μs	
T _{OFF}	Turn Off Time		-	4.2	-		
t _r	Rise Time		-	2.8	-		
t _f	Fall Time		-	4.1	-		



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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Typical Characteristic Curves

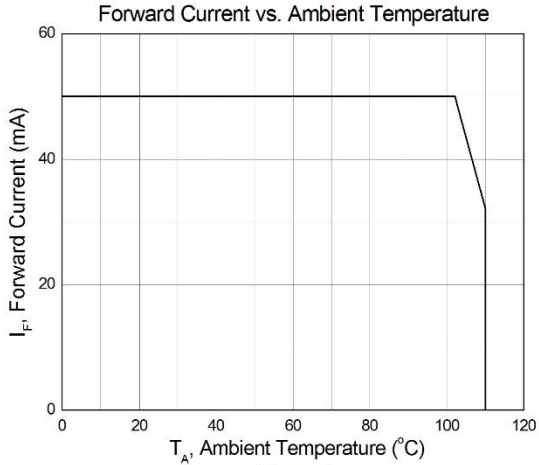


Figure 1

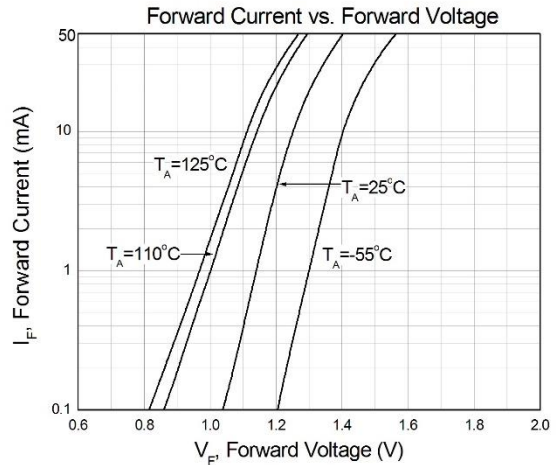


Figure 2

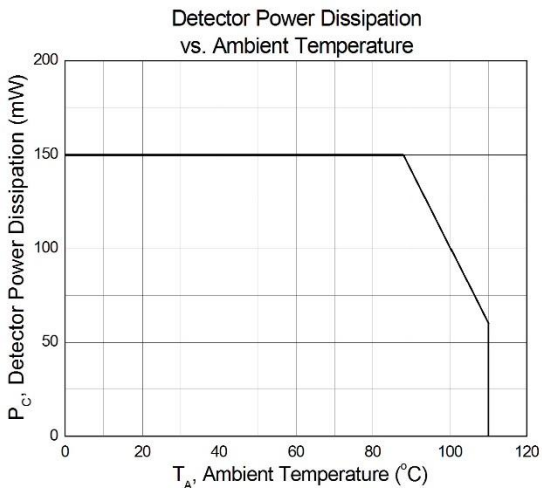


Figure 3

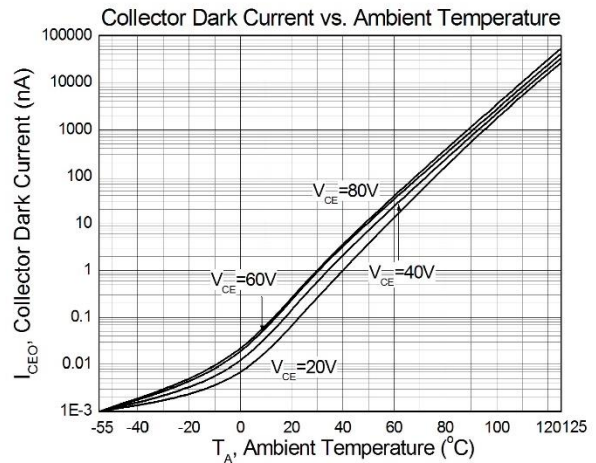


Figure 4

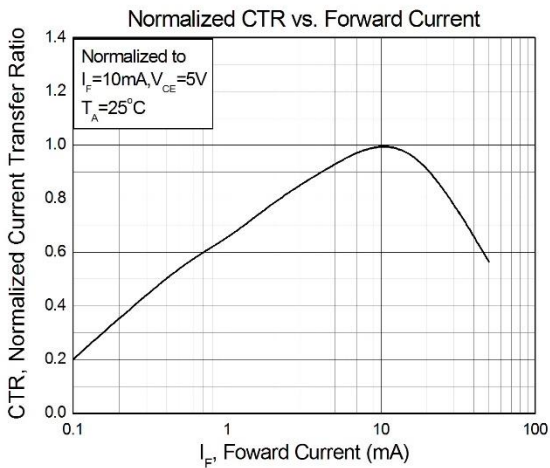


Figure 5

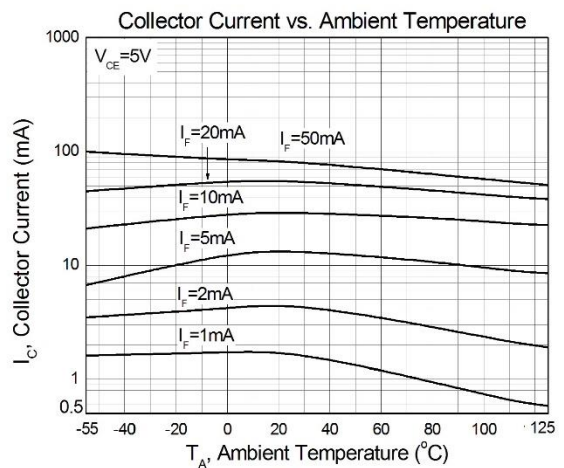


Figure 6



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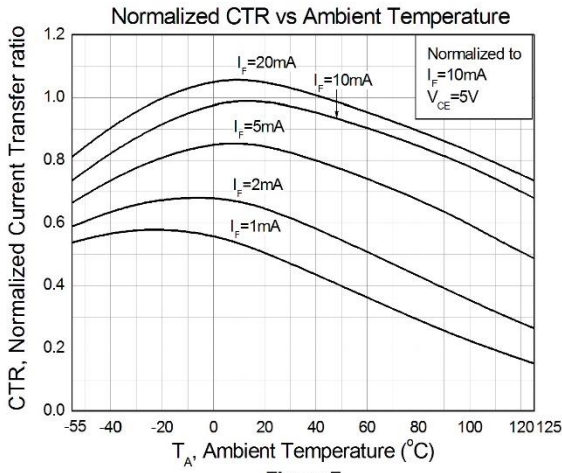


Figure 7

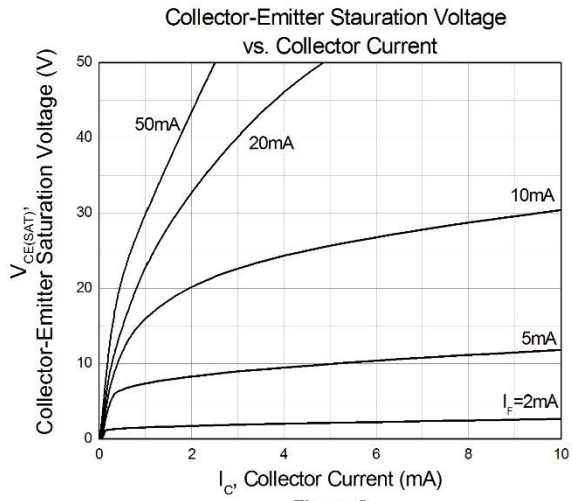


Figure 8

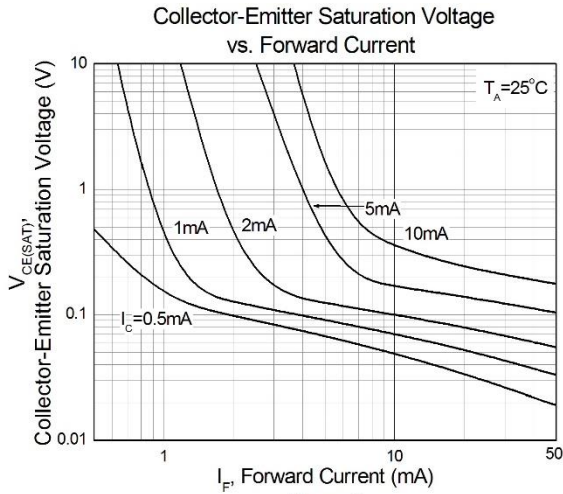


Figure 9

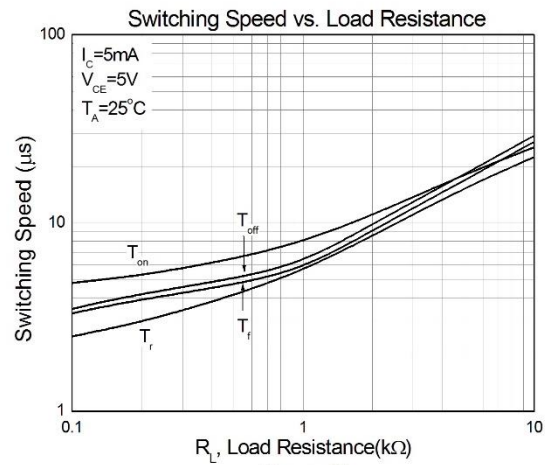
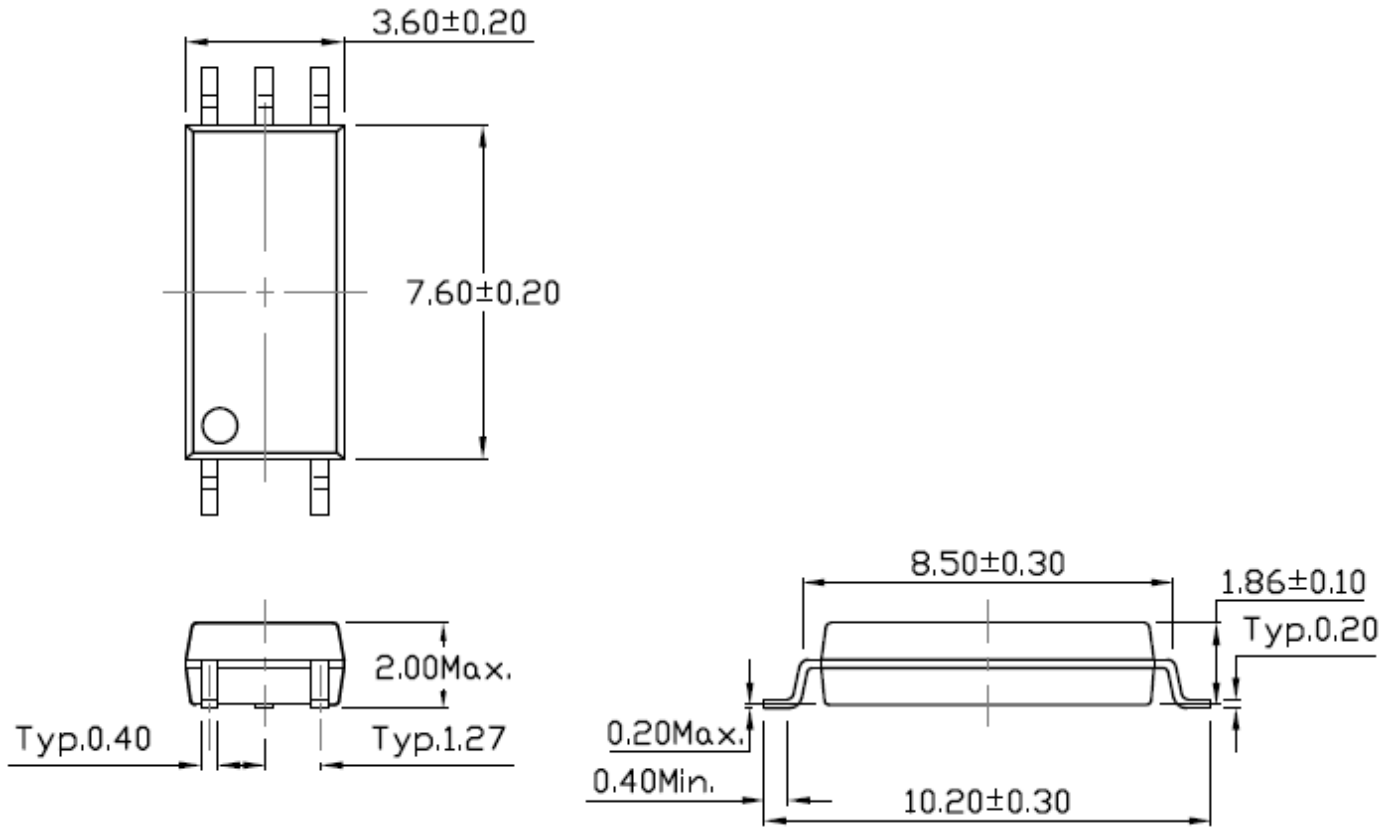


Figure 10

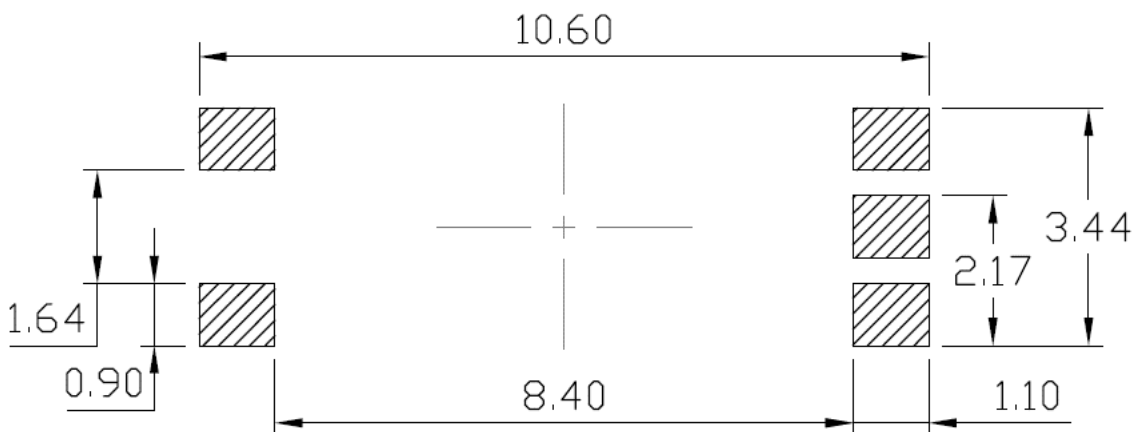


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Package Dimension *Dimensions in mm unless otherwise stated*



Recommended Solder Mask *Dimensions in mm unless otherwise stated*





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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Marking Information



Note:

- CT : Logo
- 1110 : Part Number(11XX, 11XXL)
- V : VDE Option
- Y : Fiscal Year
- WW : Work Week
- D : Manufacturing Code

Ordering Information

CT11ZX(L)(V)(Y)-W

- Z = Part No. (0,1, 2, 3, 4, 5, 6, 7, 8, 9)
- X = CTR Rank (0,1, 2, 3, 4, 5, 6, 7, 8, 9)
- L = CTR condition (L for low driver current, or None)
- V = VDE Option (V or None)
- Y = Tape and reel option (T1 or T2)
- W= Outline Color (W for white color, White only)

Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Taping	3000Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Taping	3000Units/Reel

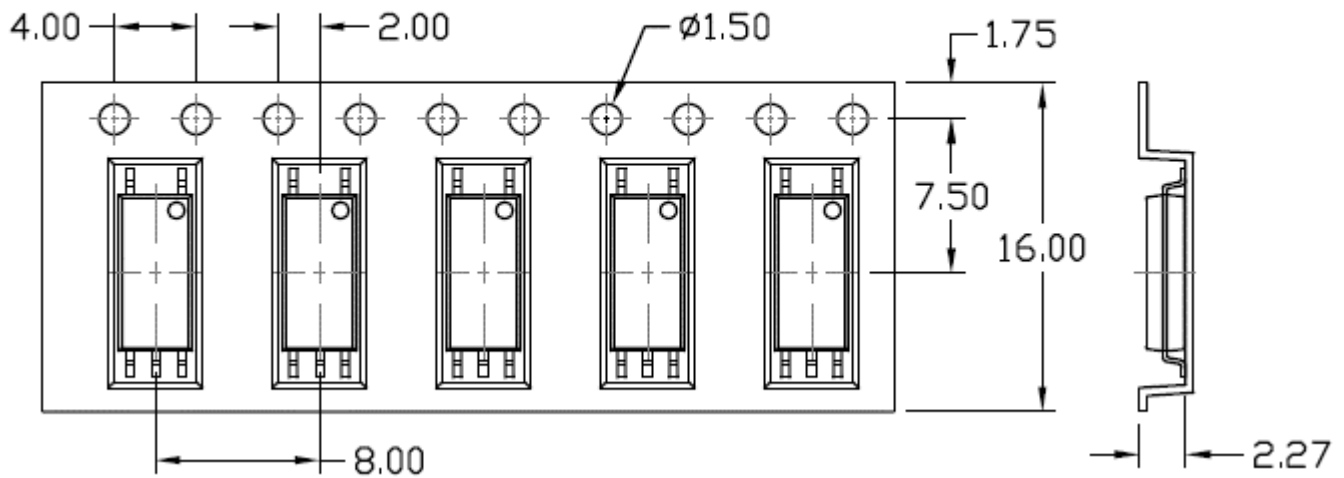


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Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

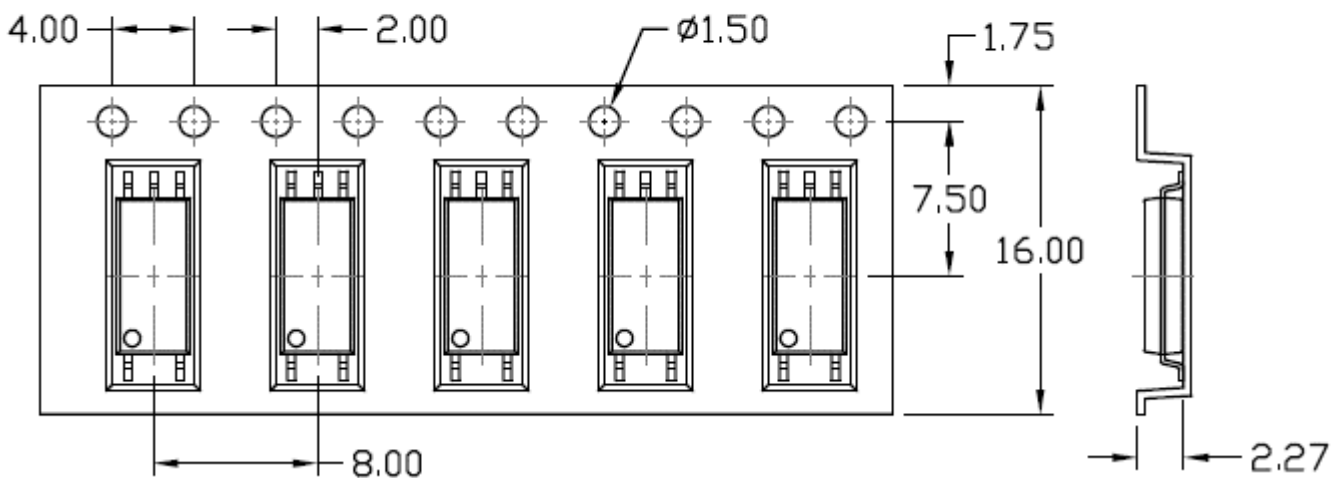
Option T1

Input Direction
→



Option T2

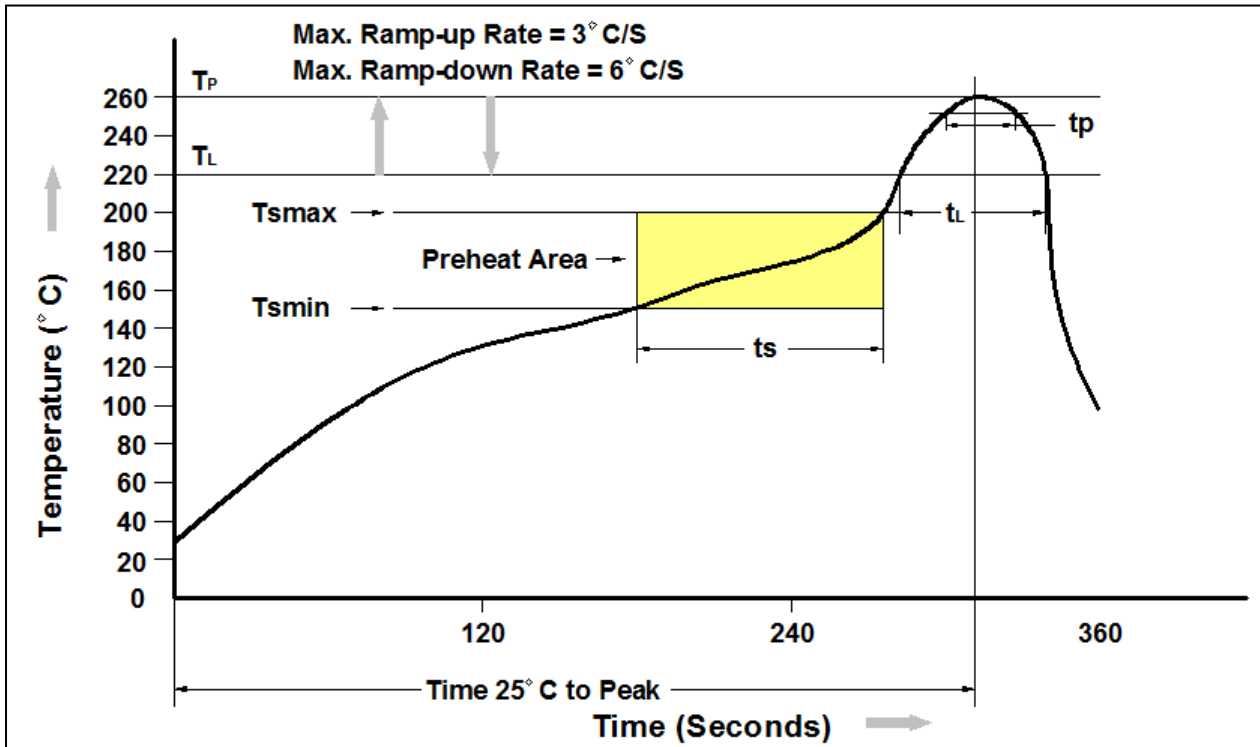
Input Direction
→





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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Reflow Profile (follow the JEDEC standard J-STD-020)



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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DC Input 5-Pin Long Mini-Flat Phototransistor Optocoupler

Wave soldering (follow the JEDEC standard JESD22-A111)

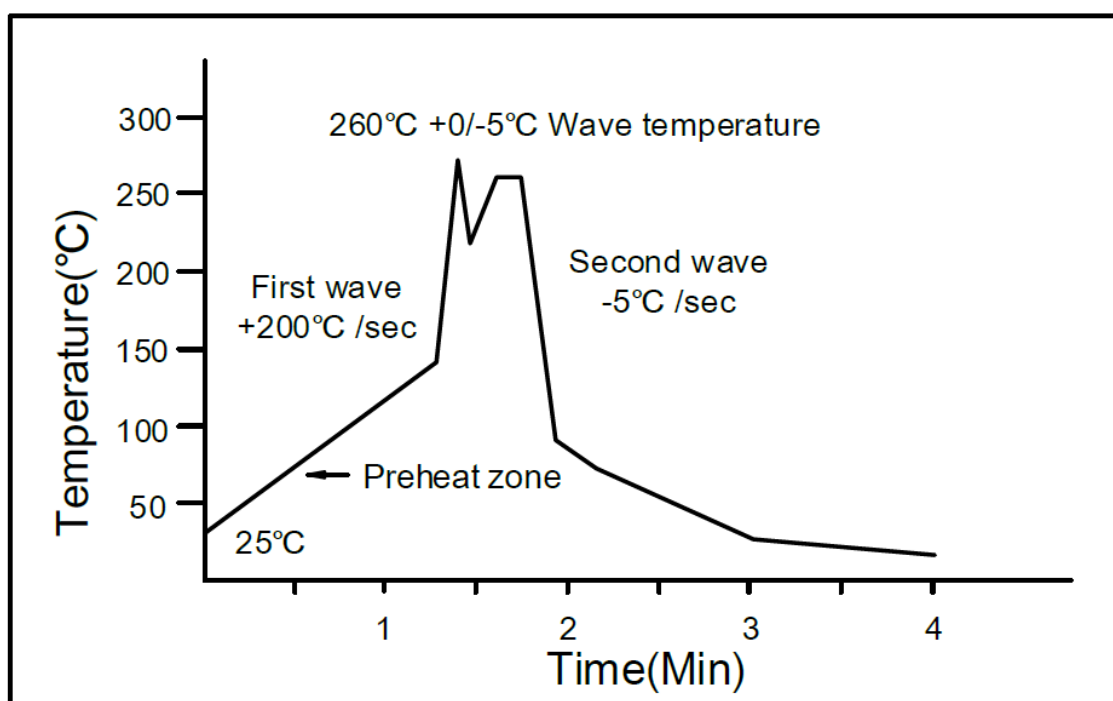
One time soldering is recommended within the condition of temperature.

Temperature: $260 \pm 0/-5^\circ\text{C}$.

Time: 10 sec.

Preheat temperature: 25 to 140°C .

Preheat time: 30 to 80 sec.



Hand soldering by soldering iron

Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: $380 \pm 0/-5^\circ\text{C}$

Time: 3 sec max.



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